National Semiconductor

PRELIMINARY

74LCX16240
Low-Voltage 16-Bit Inverting Buffer/Line Driver with 5V Tolerant Inputs/Outputs

General Description

The LCX16240 contains sixteen inverting buffers with TRI-STATE® outputs designed to be employed as a memory and address driver, clock driver, or bus-oriented transmitter/receiver. The device is nibble controlled. Each nibble has separate TRI-STATE control inputs which can be shorted together for full 16-bit operation.

The LCX16240 is designed for low voltage (3.3V) V_{CC} applications with capacity of interfacing to a 5V signal environment.

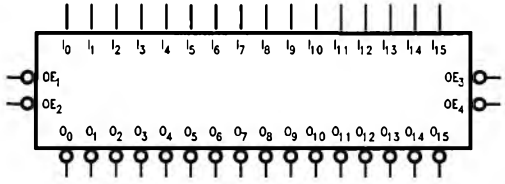
The LCX16240 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- Ideal for low power/low noise 2.7V to 3.6V applications
- Power-down static overvoltage protection on inputs and outputs
- Outputs source/sink 24 mA
- Guaranteed simultaneous switching noise level
- Available in SSOP and TSSOP
- Implements patented Quiet Series noise/EMI reduction circuitry
- Functionally compatible with the 74 series 16240
- Latchup performance exceeds 300 mA
- ESD performance:
  Human body model >2500V
  Machine model >250V

Ordering Code: See Section 11

Logic Symbol



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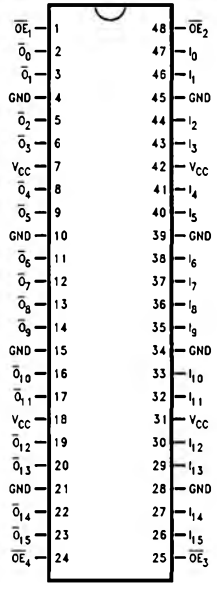
Pin Names	Description
$\overline{OE}_n$	Output Enable Inputs (Active Low)
I_0–I_{15}	Inputs
$\overline{O}_0$–$\overline{O}_{15}$	Outputs

	SSOP EIAJ	TSSOP JEDEC
Order Number	74LCX16240MEA 74LCX16240MEAX	74LCX16240MTD 74LCX16240MTDX
See NS Package Number	MS48A	MTD48

Connection Diagram

Pin Assignment for SSOP and TSSOP



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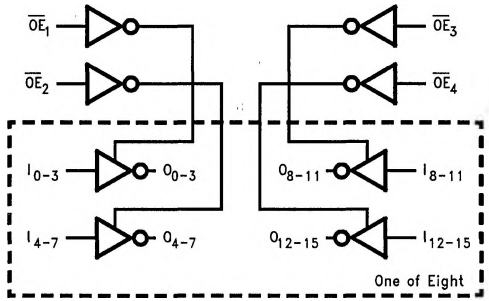
Preliminary Data: National Semiconductor reserves the right to make changes at any time without notice.

Functional Description

The LCX16240 contains sixteen inverting buffers with TRI-STATE standard outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins may be shorted together to obtain full 16-bit operation. The TRI-STATE outputs are controlled by an Output Enable ($\overline{OE}_n$) input for each nibble. When $\overline{OE}_n$ is LOW, the outputs are in 2-state mode. When $\overline{OE}_n$ is HIGH, the outputs are in the high impedance mode, but this does not interfere with entering new data into the inputs.

Logic Diagram



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Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_0–I_3	$\overline{O}_0$–$\overline{O}_3$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_4–I_7	$\overline{O}_4$–$\overline{O}_7$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_3$	I_8–I_{11}	$\overline{O}_8$–$\overline{O}_{11}$
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_4$	I_{12}–I_{15}	$\overline{O}_{12}$–$\overline{O}_{15}$
L	L	H
L	H	L
H	X	Z

H = High Voltage Level
L = Low Voltage Level
X = Immaterial
Z = High Impedance

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Voltage (V_I)	−0.5V to +7.0V
Output Voltage (V_O)	
Output TRI-STATE	−0.5V to +7.0V
Outputs Active (Note 2)	−0.5V to V_{CC} +0.5V
DC Input Diode Current (I_{IK}) $V_I < 0$	−50 mA
DC Output Diode Current (I_{OK})	
$V_O < 0$	−50 mA
$V_O > V_{CC}$	+50 mA
DC Output Source/Sink Curr. (I_{OH}/I_{OL})	±50 mA
DC V_{CC} or Ground Current per Supply Pin (I_{CC} or I_{GND})	±100 mA
Storage Temperature Range (TSTG)	−65°C to +150°C

Note 1: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Note 2: *I_O Absolute Maximum Rating must be observed.*

Recommended Operating Conditions

Supply Voltage	
Operating	2.0V to 3.6V
r Data Retention only	1.5V to 3.6V
Input Voltage (V_I)	0.0V to 5.5V
Output Voltage (V_O)	
Output in Active State	0.0V to V_{CC}
Output in "OFF" State	0.0V to 5.5V
Output Current I_{OH}/I_{OL}	
V_{CC} = 3.0V to 3.6V	±24 mA
V_{CC} = 2.7V to 3.0V	±12 mA
Free Air Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate ($\Delta t/\Delta V$)	
V_{IN} = 0.8V to 2.0V, V_{CC} = 3.0V	10 ns/V

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = −40°C to +85°C		Units	Conditions
			Min	Max		
V_{IH}	High Level Input Voltage	2.7–3.6	2.0		V	$V_{OUT} \le 0.1V$ or $\ge V_{CC} - 0.1V$
V_{IL}	Low Level Input Voltage	2.7–3.6		0.8		
V_{OH}	High Level Output Voltage	2.7–3.6	$V_{CC}-0.2$		V	I_{OH} = −100 μA
		2.7	2.2			I_{OH} = −12 mA
		3.0				I_{OH} = −18 mA
		3.0	2.2			I_{OH} = −24 mA
V_{OL}	Low Level Output Voltage	2.7–3.6		0.2	V	I_{OL} = 100 μA
		2.7		0.4		I_{OL} = 12 mA
		3.0		0.55		I_{OL} = 24 mA
I_I	Input Leakage Current	2.7–3.6		±5.0	μA	$0 \le V_I \le 5.5V$
I_{OZ}	TRI-STATE Output Leakage	2.7–3.6		±5.0	μA	$0 \le V_O \le 5.5V$ $V_I = V_{IH}$ or V_{IL}
I_{CC}	Quietscent Supply Current	2.7–3.6		20	μA	$V_I = V_{CC}$ or GND
				±20	μA	$3.6 \le (V_I, V_O) \le 5.5V$
ΔI_{CC}	Increase in I_{CC} per Input	2.7–3.6		500	μA	$V_{IH} = V_{CC} - 0.6V$
I_{OFF}	Power Off Leakage Current	0		100	μA	V_I or V_O = 5.5V

AC Electrical Characteristics: See Section 2 for test methodology

Symbol	Parameter	V_{CC} (V)	$T_A = -40°C$ to $+85°C$, $C_L = 50$ pF		Units
			Min	Max (Note 2)	
t_{PHL}, t_{PLH}	Propagation Delay Data to Output	2.7 3.0–3.6	1.5 1.5	5.6 4.9	ns
t_{PZL}, t_{PZH}	Output Enable Time	2.7 3.0–3.6	1.5 1.5	7.7 7.0	ns
t_{PHZ}, t_{PLZ}	Output Disable Time	2.7 3.0–3.6	1.5 1.5	7.7 7.0	ns
t_{OSHL}, t_{OSLH}	Output to Output Skew (Note 1)	3.0		1.0	ns

Note 1. Skew is defined as the absolute value of the difference between the actual propagaton delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

Note 2. The maximum AC limits are design targets. Actual performance will be specified upon completion of characterization.

Dynamic Switching Characteristics: See Section 2 for test methodology

Symbol	Parameter	V_{CC} (V)	$T_A = 25°C$ Typical	Units	Conditions
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	3.3	0.8	V	$C_L = 50$ pF, $V_{IH} = 3.3$V, $V_{IL} = 0$V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	3.3	0.8	V	$C_L = 50$ pF, $V_{IH} = 3.3$V, $V_{IL} = 0$V

Capacitance

Symbol	Parameter	Typical	Units	Conditions
C_{IN}	Input Capacitance	7	pF	V_{CC} = Open $V_I = 0$V or V_{CC}
C_{OUT}	Output Capacitance	8	pF	$V_{CC} = 3.3$V $V_I = 0$V or V_{CC}
C_{PD}	Power Dissipation Capacitance	32	pF	$V_{CC} = 3.3$V $V_I = 0$V or V_{CC} F = 10 MHz